## Accepted Manuscript

Title: Electrochemical Behaviour of Manganese and Ruthenium mixed Oxide@ Reduced Graphene Oxide Nanoribbon Composite in Symmetric and Asymmetric Supercapacitor

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PII: S0169-4332(17)32354-1

DOI: http://dx.doi.org/doi:10.1016/j.apsusc.2017.08.028

Reference: APSUSC 36865

To appear in: APSUSC

Received date: 7-3-2017 Revised date: 27-6-2017 Accepted date: 3-8-2017

Please cite this article as: Preety Ahuja, Sanjeev Kumar Ujjain, Rajni Kanojia, Electrochemical Behaviour of Manganese and Ruthenium mixed Oxide@ Reduced Graphene Oxide Nanoribbon Composite in Symmetric and Asymmetric Supercapacitor, Applied Surface Sciencehttp://dx.doi.org/10.1016/j.apsusc.2017.08.028

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## ACCEPTED MANUSCRIPT

## Electrochemical Behaviour of Manganese & Ruthenium mixed Oxide@ Reduced Graphene Oxide Nanoribbon Composite in Symmetric and Asymmetric Supercapacitor

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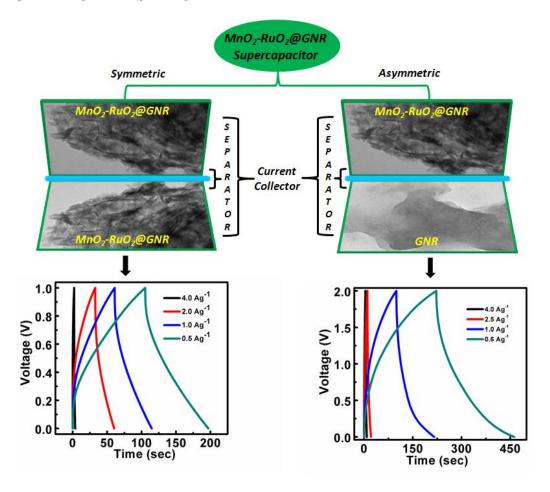
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#### **GRAPHICAL ABSTRACT**



MnO<sub>2</sub>-RuO<sub>2</sub>@GNR shows enhanced capacitive performance in symmetric and asymmetric assembly with GNR resulting in high ED and PD.

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